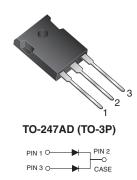


Vishay General Semiconductor

## **Dual Common-Cathode Schottky Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 40 A					
$V_{RRM}$	35 V to 60 V				
I <sub>FSM</sub>	400 A				
$V_{F}$	0.60 V, 0.62 V				
T <sub>J</sub> max.	150 °C				

#### **FEATURES**

• Guardring for overvoltage protection



· Lower power losses, high efficiency



Low forward voltage drop

RoHS

High forward surge capability

· High frequency operation

• Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	<sub>/M</sub> 35 45		50	60	V	
Maximum DC blocking voltage	V <sub>DC</sub> 35 45		50	60	V		
Maximum average forward rectified current at $T_C$ = 125 $^{\circ}C$	I <sub>F(AV)</sub>	40					
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	400				Α	
Peak repetitive reverse surge current per diode (1)	I <sub>RRM</sub>	2.0 1.0		.0	Α		
Voltage rate of change at (rated V <sub>R</sub> )	dV/dt	10 000				V/µs	
Operating junction temperature range	TJ	- 65 to + 150			°C		
Storage temperature range	T <sub>STG</sub>	- 65 to + 175 °C				°C	

#### Note:

(1) 2.0  $\mu$ s pulse width, f = 1.0 kHz

### MBR4035PT thru MBR4060PT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS		SYMBOL	MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT	
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	$I_F = 20 \text{ A},$ $I_F = 20 \text{ A},$ $I_F = 40 \text{ A},$ $I_F = 40 \text{ A},$	$T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ $T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$	V <sub>F</sub>	0.70 0.60 0.80 0.75			72 62 - -	٧	
Maximum instantaneous reverse current at rated DC blocking voltage per diode (1)		T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	I <sub>R</sub>	1.0 100			mA		

#### Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT
Maximum thermal resistance from junction to case per diode	$R_{ heta JC}$	1.2			°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	GE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE				DELIVERY MODE		
TO-247AD	MBR4045PT-E3/45	6.13	45	30/tube	Tube		

#### **RATINGS AND CHARACTERISTICS CURVES**

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$ 

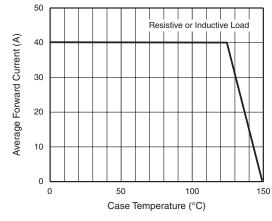


Figure 1. Forward Current Derating Curve

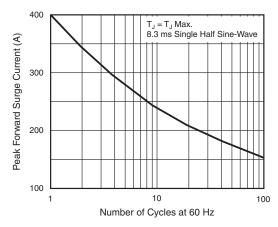


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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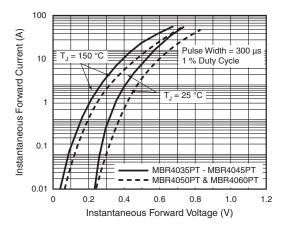


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

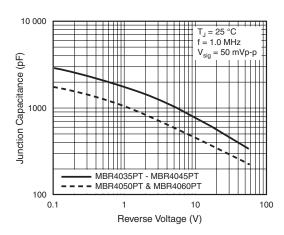


Figure 5. Typical Junction Capacitance Per Diode

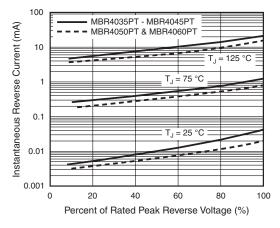


Figure 4. Typical Reverse Characteristics Per Diode

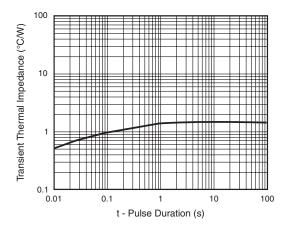
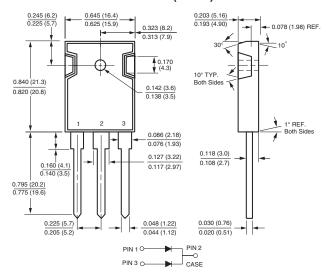


Figure 6. Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### TO-247AD (TO-3P)





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